

1. Global joint venture starts operations as WeEn Semiconductors

Dear customer,

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

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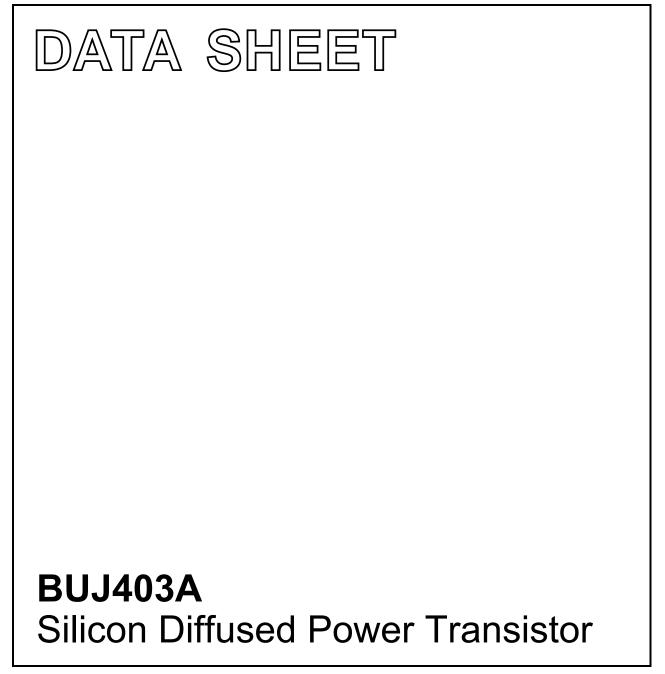
If you have any questions related to this document, please contact our nearest sales office via email or phone (details via <u>salesaddresses@ween-semi.com</u>).

Thank you for your cooperation and understanding,

WeEn Semiconductors



DISCRETE SEMICONDUCTORS



Product specification

December 1998



BUJ403A

GENERAL DESCRIPTION

High-voltage, high-speed planar-passivated npn power switching transistor in TO220AB envelope intended for use in high frequency electronic lighting ballast applications, converters, inverters, switching regulators, motor control systems, etc.

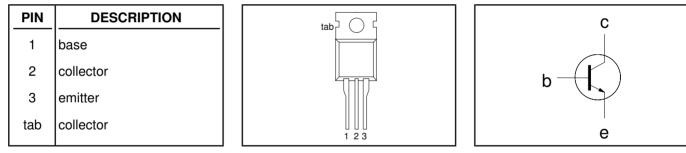
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0 V$	-	1200	V
V _{CBO}	Collector-Base voltage (open emitter)		-	1200	V
V _{CEO}	Collector-emitter voltage (open base)		-	550	V
	Collector current (DC)		-	6	A
l ı [°]	Collector current peak value		-	10	Α
P _{tot}	Total power dissipation	T _{mb} ≤ 25 °C	-	100	W
V _{CEsat}	Collector-emitter saturation voltage	$I_{\rm C} = 2 \text{ A}; I_{\rm B} = 0.4 \text{ A}$	0.15	1.0	V
h _{FEsat}	DC current gain	$I_{c} = 3 \text{ A}; V_{ce} = 5 \text{ V}$	15.5	-	
t _f	Fall time	$I_{C} = 2.5 \text{ Å}; I_{B1} = 0.5 \text{ A}$	170	300	ns

PINNING - TO220AB

PIN CONFIGURATION

SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CESM}	Collector to emitter voltage	$V_{BE} = 0 V$	-	1200	V
V _{CEO}	Collector to emitter voltage (open base)		-	550	V
V _{CBO}	Collector to base voltage (open emitter)		-	1200	V
I _C	Collector current (DC)		-	6	Α
I _{CM}	Collector current peak value		-	10	Α
I _B	Base current (DC)		-	3	Α
I _{BM}	Base current peak value		-	5	Α
	Total power dissipation	T _{mb} ≤ 25 °C	-	100	W
T _{stg}	Storage temperature		-65	150	°C
	Junction temperature		-	150	°C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R _{th i-mb}	Junction to mounting base		-	1.25	K/W
R _{th i-a}	Junction to ambient	in free air	60	-	K/W

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STATIC CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CES} ,I _{CBO} I _{CES}	Collector cut-off current ¹		-	-	1.0 2.0	mA mA
I _{CEO} I _{EBO} V _{CEOsust}	Collector cut-off current ¹ Emitter cut-off current Collector-emitter sustaining voltage		- - 550	- - -	0.1 0.1 -	mA mA V
$\begin{array}{l} V_{CEsat} \\ V_{BEsat} \\ h_{FE} \\ h_{FE} \\ h_{FEsat} \\ h_{FEsat} \end{array}$	Collector-emitter saturation voltage Base-emitter saturation voltage DC current gain DC current gain	$I_{c} = 2.0 \text{ A}; I_{B} = 0.4 \text{ A}$ $I_{c} = 2.0 \text{ A}; I_{B} = 0.4 \text{ A}$ $I_{c} = 1 \text{ mA}; V_{CE} = 5 \text{ V}$ $I_{c} = 500 \text{ mA}; V_{CE} = 5 \text{ V}$ $I_{c} = 2.0 \text{ A}; V_{CE} = 5 \text{ V}$ $I_{c} = 3.0 \text{ A}; V_{CE} = 5 \text{ V}$	- 13 20 13 -	0.15 0.91 25 30 18.5 15.5	1.0 1.5 - 47 25 -	V V

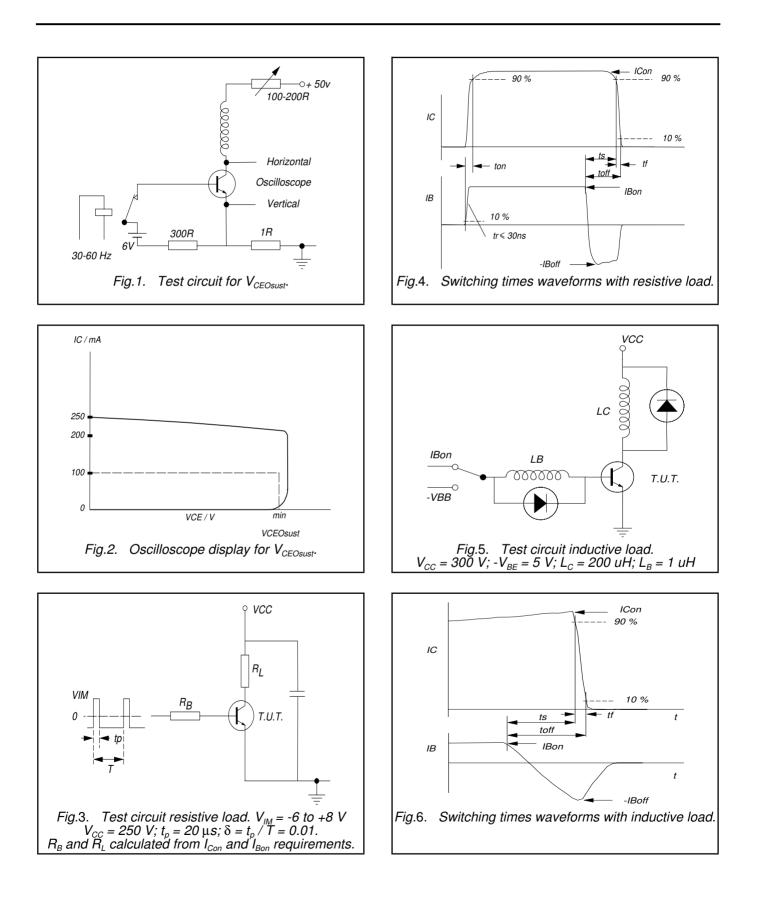
DYNAMIC CHARACTERISTICS

 $T_{mb} = 25 \degree C$ unless otherwise specified

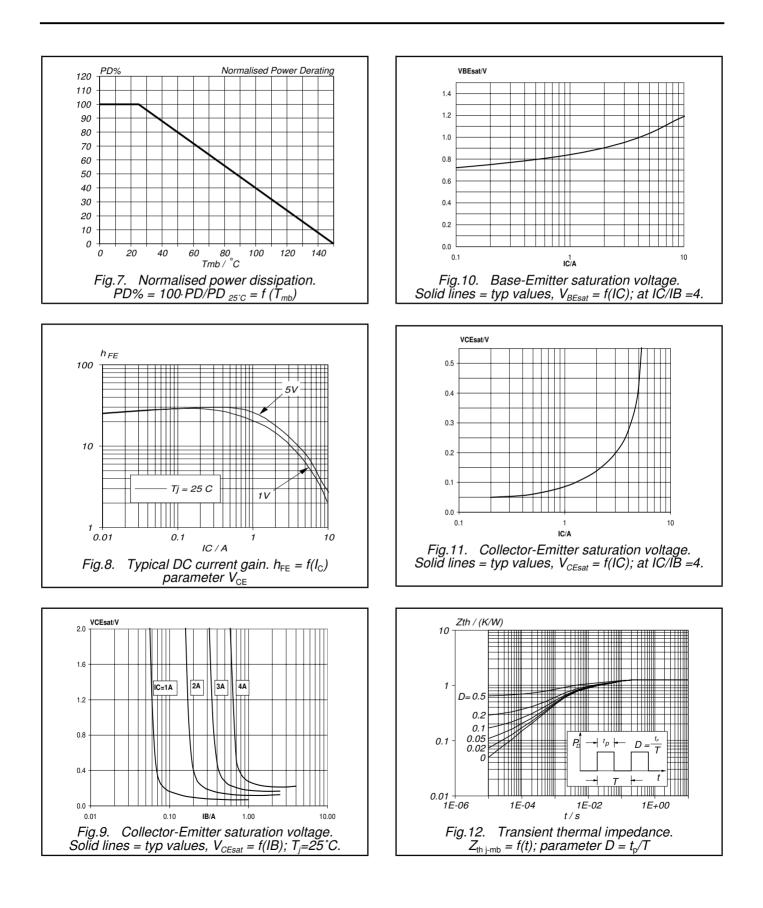
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
	Switching times (resistive load)	$I_{Con} = 2.5 \text{ A}; I_{Bon} = -I_{Boff} = 0.5 \text{ A};$ R ₁ = 75 ohms; V _{BB2} = 4 V;			
t _{on}	Turn-on time		-	0.5	μs
ts	Turn-off storage time		-	3	μs
t _f	Turn-off fall time		-	0.3	μs
	Switching times (inductive load)	$I_{Con} = 2.5 \text{ A}; I_{Bon} = 0.5 \text{ A}; L_{B} = 1 \ \mu\text{H};$ -V _{BB} = 5 V			
t _s	Turn-off storage time		-	1.5	μs
t _f	Turn-off fall time		170	300	ns
	Switching times (inductive load)	$I_{Con} = 2.5 \text{ A}; I_{Bon} = 0.5 \text{ A}; L_{B} = 1 \ \mu\text{H}; -V_{BB} = 5 \ V; T_{i} = 100 \ ^{\circ}\text{C}$			
ts	Turn-off storage time		-	1.8	μs
tř	Turn-off fall time		-	300	ns

¹ Measured with half sine-wave voltage (curve tracer).

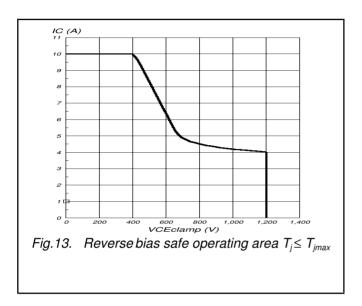
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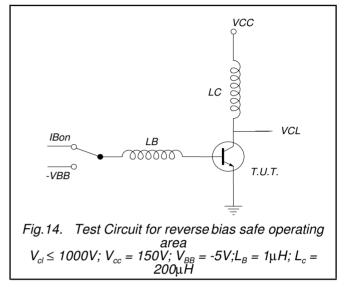


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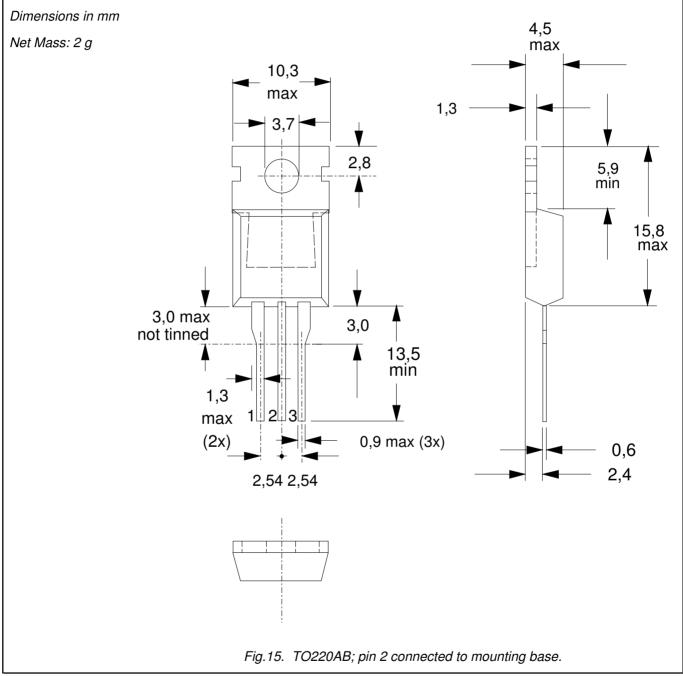
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MECHANICAL DATA



Notes 1. Refer to mounting instructions for TO220 envelopes. 2. Epoxy meets UL94 V0 at 1/8".

Legal information

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Contact information

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